NSN 5961-00-774-8218

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-774-8218 **Inclosure Material:** Metal **Overall Length:** 1.237 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes source cutoff current minor **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 4.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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